

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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## 2SK3228

Silicon N Channel MOS FET  
High Speed Power Switching

REJ03G1094-0400

Rev.4.00

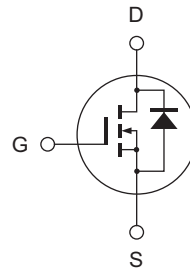
May 15, 2006

### Features

- Low on-resistance  
 $R_{DS(on)} = 6\text{ m}\Omega$  typ.
- Low drive current
- 4 V gate drive device can be driven from 5 V source

### Outline

RENESAS Package code: PRSS0004AC-A  
(Package name: TO-220AB)



1. Gate
2. Drain (Flange)
3. Source

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	80	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	75	A
Drain peak current	I <sub>D (pulse)</sub> <sup>Note 1</sup>	300	A
Body-drain diode reverse drain current	I <sub>DR</sub>	75	A
Avalanche current	I <sub>AP</sub> <sup>Note 3</sup>	50	A
Avalanche energy	E <sub>AR</sub> <sup>Note 3</sup>	181	mJ
Channel dissipation	P <sub>ch</sub> <sup>Note 2</sup>	100	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%  
 2. Value at T<sub>c</sub> = 25°C  
 3. Value at T<sub>ch</sub> ≤ 25°C, R<sub>g</sub> ≥ 50 Ω

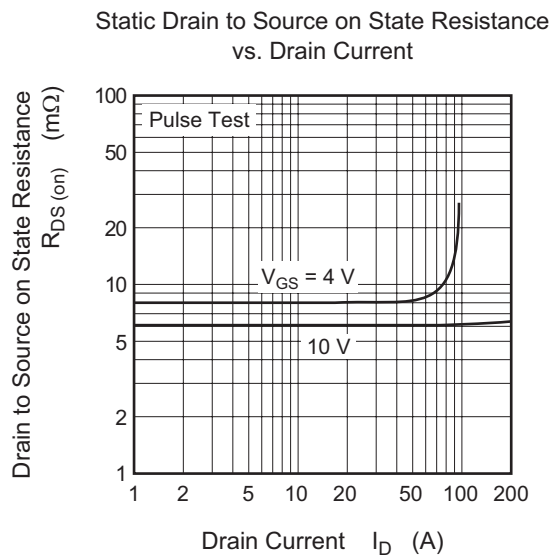
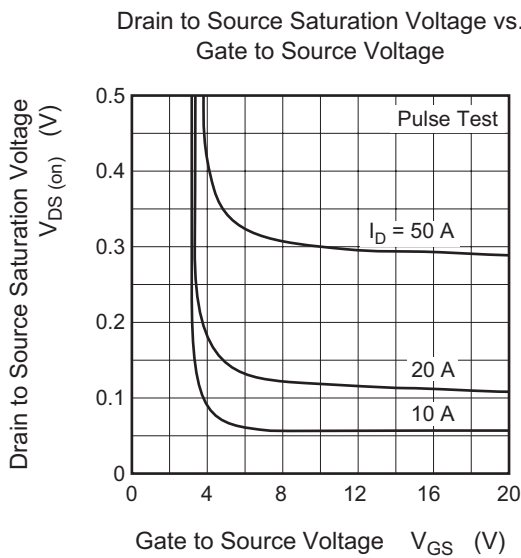
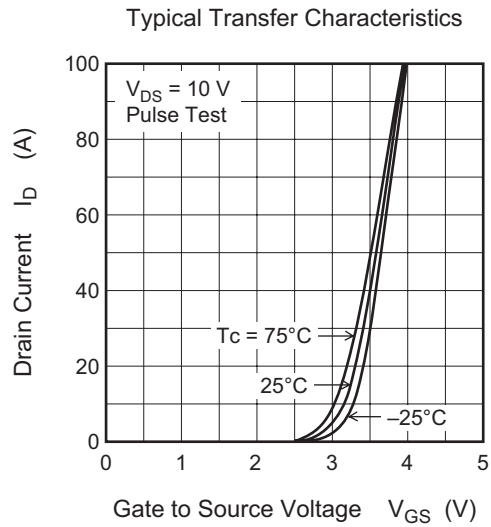
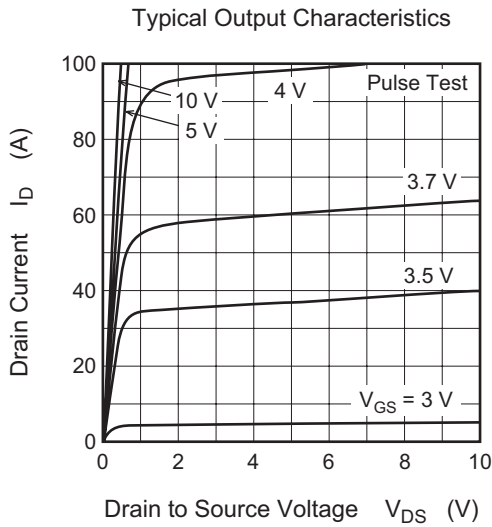
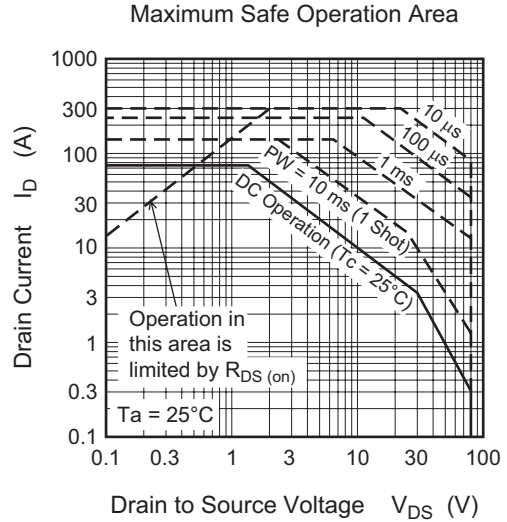
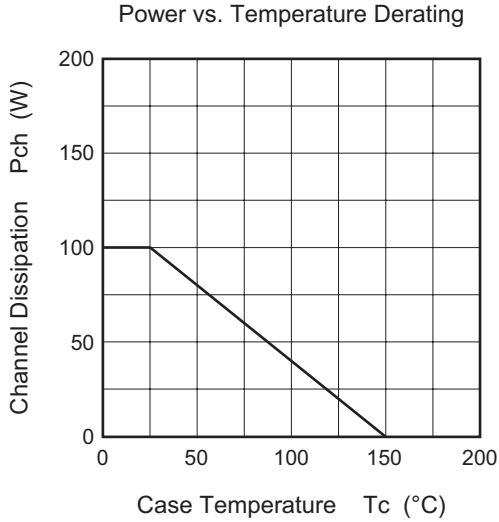
## Electrical Characteristics

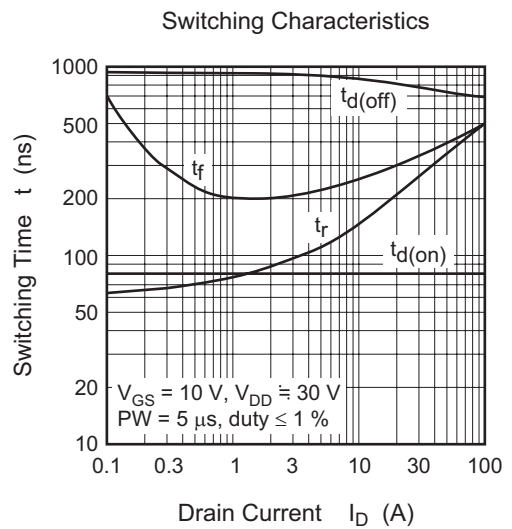
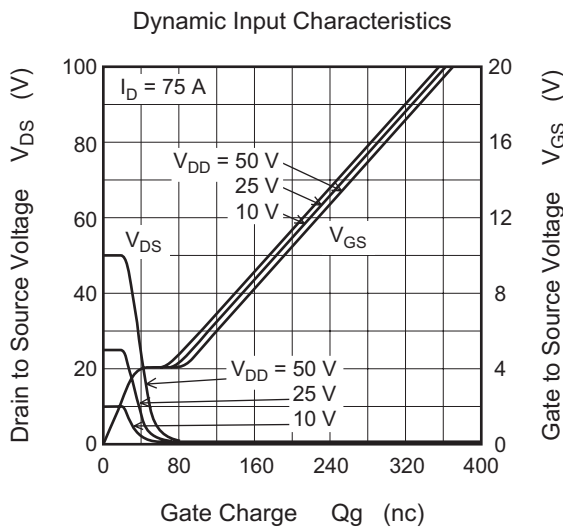
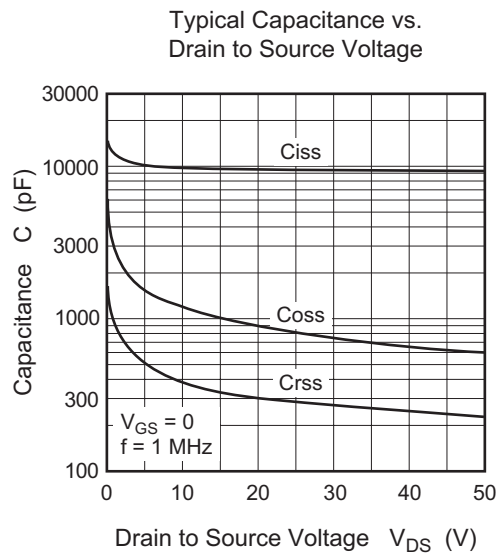
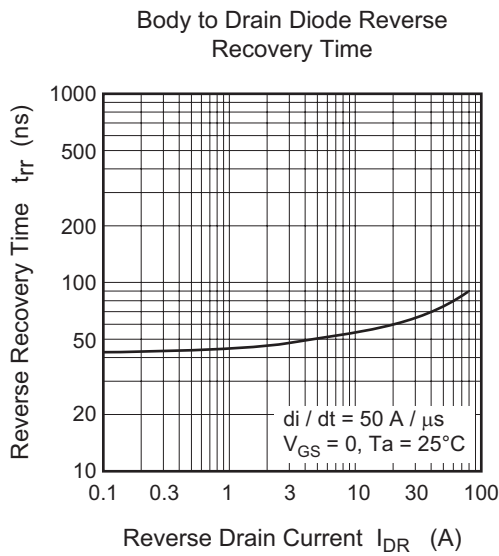
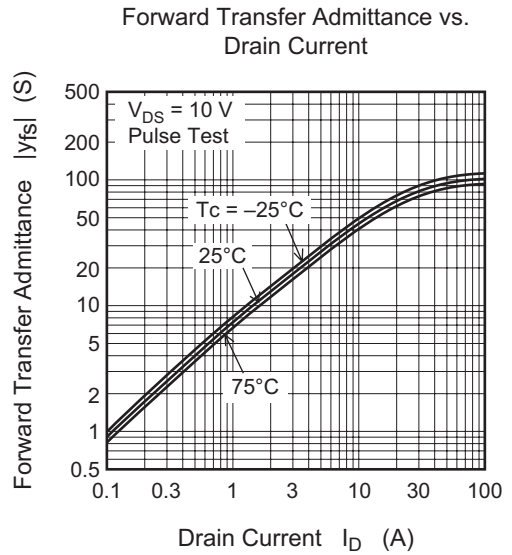
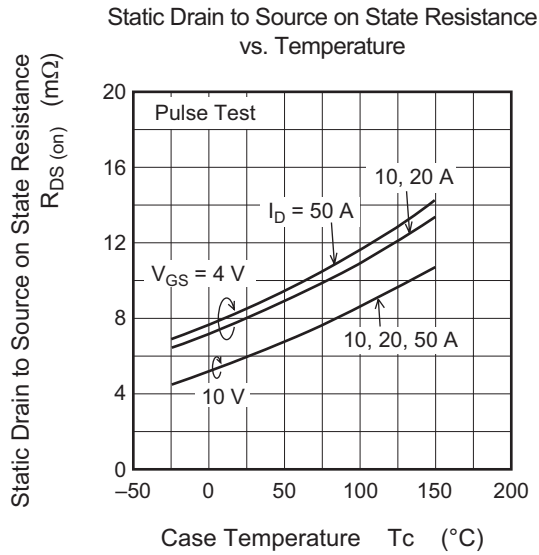
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	80	—	—	V	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0
Gate to source leak current	I <sub>GSS</sub>	—	—	±0.1	μA	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0
Zero gate voltage drain current	I <sub>DSS</sub>	—	—	10	μA	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0
Gate to source cutoff voltage	V <sub>GS (off)</sub>	1.0	—	2.5	V	I <sub>D</sub> = 1 mA, V <sub>DS</sub> = 10 V
Static drain to source on state resistance	R <sub>DS (on)</sub>	—	6.0	7.5	mΩ	I <sub>D</sub> = 40 A, V <sub>GS</sub> = 10 V <sup>Note 4</sup>
	R <sub>DS (on)</sub>	—	8.0	12	mΩ	I <sub>D</sub> = 40 A, V <sub>GS</sub> = 4 V <sup>Note 4</sup>
Forward transfer admittance	y <sub>fs</sub>	55	90	—	S	I <sub>D</sub> = 40 A, V <sub>DS</sub> = 10 V <sup>Note 4</sup>
Input capacitance	C <sub>iss</sub>	—	9700	—	pF	I <sub>D</sub> = 10 V V <sub>GS</sub> = 0 f = 1 MHz
Output capacitance	C <sub>oss</sub>	—	1250	—	pF	
Reverse transfer capacitance	C <sub>rss</sub>	—	290	—	pF	
Total gate charge	Q <sub>g</sub>	—	150	—	nC	V <sub>DD</sub> = 25 V
Gate to source charge	Q <sub>gs</sub>	—	30	—	nC	V <sub>GS</sub> = 25 V
Gate to drain charge	Q <sub>gd</sub>	—	30	—	nC	I <sub>D</sub> = 75 A
Turn-on delay time	t <sub>d (on)</sub>	—	80	—	ns	I <sub>D</sub> = 10 A V <sub>GS</sub> = 40 V R <sub>L</sub> = 0.75 Ω
Rise time	t <sub>r</sub>	—	300	—	ns	
Turn-off delay time	t <sub>d (off)</sub>	—	770	—	ns	
Fall time	t <sub>f</sub>	—	370	—	ns	
Body-drain diode forward voltage	V <sub>DF</sub>	—	1.05	—	V	I <sub>F</sub> = 75 A, V <sub>GS</sub> = 0
Body-drain diode reverse recovery time	t <sub>rr</sub>	—	90	—	ns	I <sub>F</sub> = 75 A, V <sub>GS</sub> = 0 di <sub>F</sub> /dt = 50 A/μs

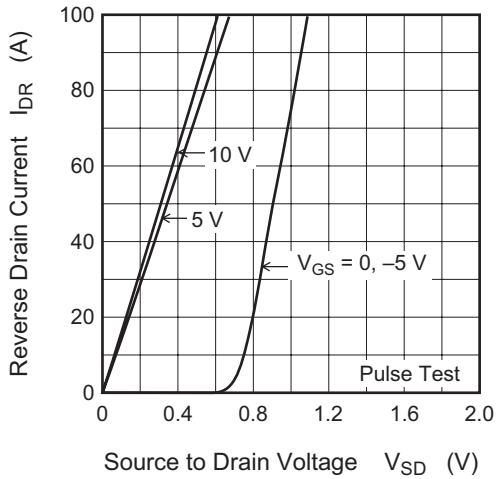
Note: 4. Pulse test

Main Characteristics

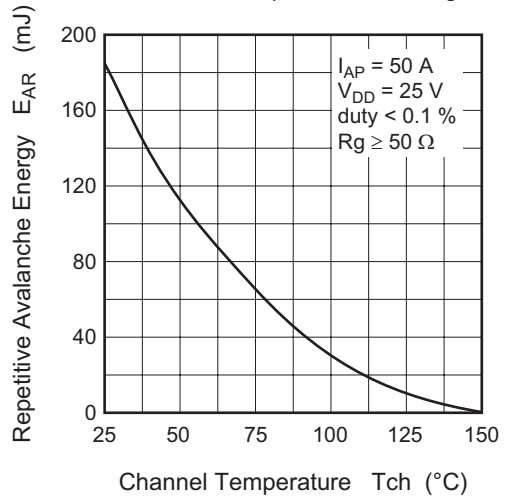




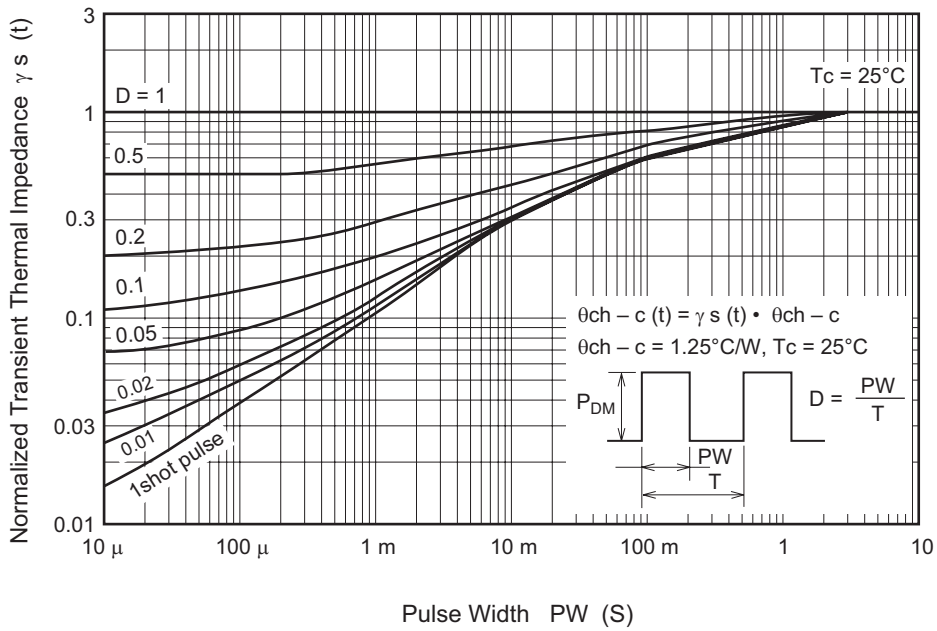
Reverse Drain Current vs. Source to Drain Voltage



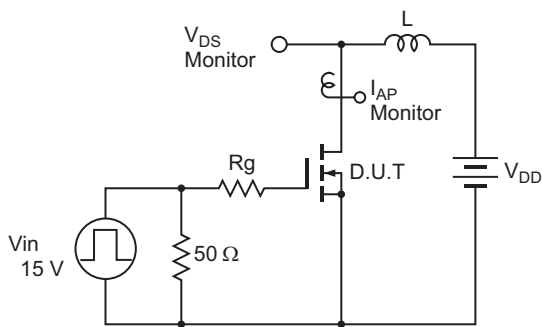
Maximum Avalanche Energy vs. Channel Temperature Derating



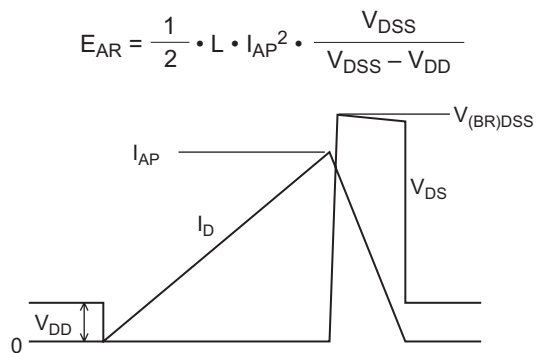
Normalized Transient Thermal Impedance vs. Pulse Width

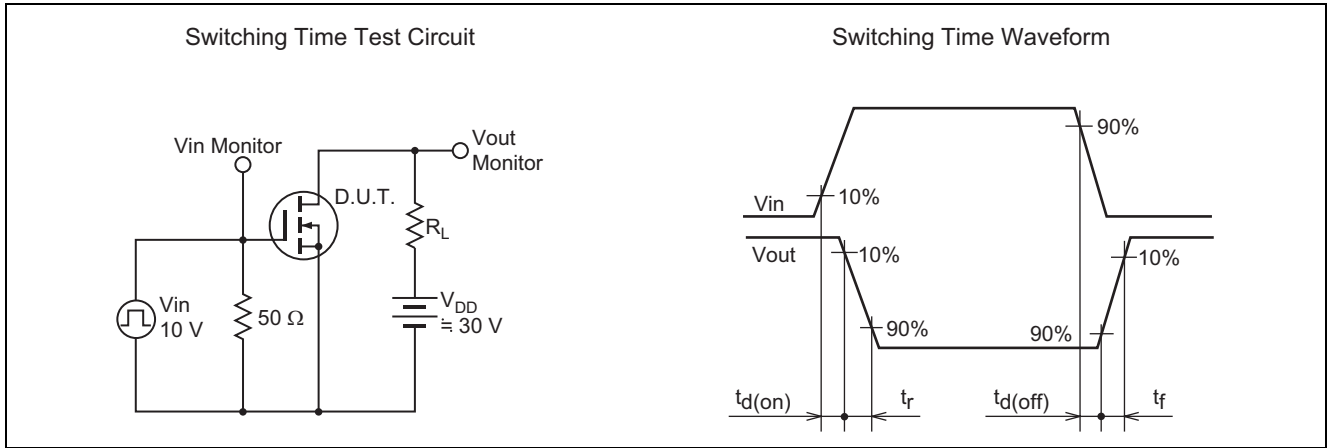


Avalanche Test Circuit



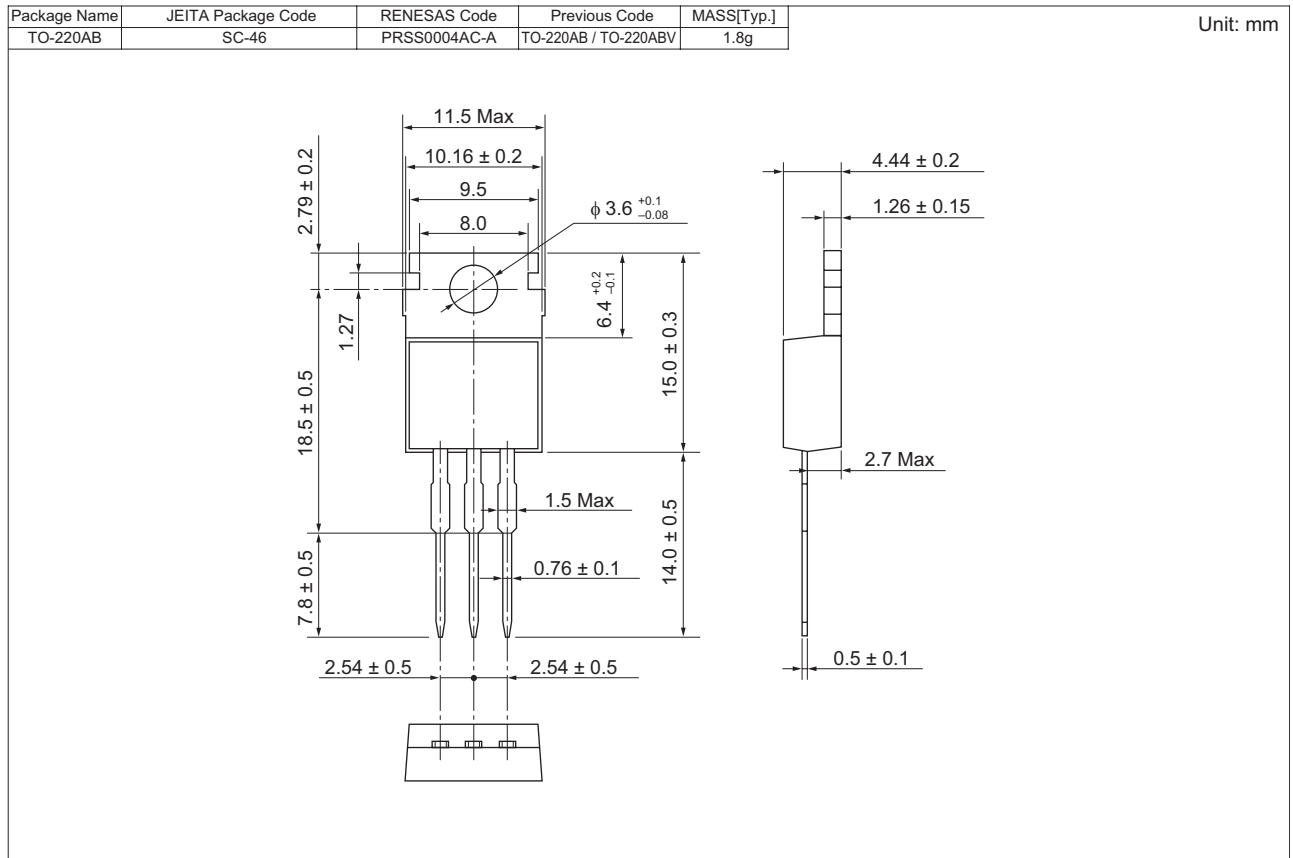
Avalanche Waveform







## Package Dimensions



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Part Name	Quantity	Shipping Container
2SK3228-E	500 pcs	Box (Sack)

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